

Hexagonal Boron Nitride Nanosheets Grown via Chemical Vapor Deposition for Silver Protection

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KEYWORDS

2D materials; hexagonal boron nitride; nanosheets; chemical vapor deposition; silver anticorrosion; protective coatings

ABSTRACT

In this study, hexagonal boron nitride nanosheets (h-BNNS) have been grown on polycrystalline silver substrates via chemical vapor deposition (CVD) using ammonia borane as a precursor. The h-BNNS are of few-atomic-layer thickness and form continuous coverage over the whole Ag substrate. The atomically thin coating poses negligible interference to the reflectivity in the UV-visible range. The nanosheet coating also proves very effective in protecting Ag foil chemically. In contrast to bare Ag foil, the coated one displayed only minor decolorization under high

concentration of H₂S. The study indicates that h-BNNS can be a promising protective coating for Ag based items such as jewelry or mirrors used in astronomical telescopes.

INTRODUCTION

Two-dimensional (2D) materials with thickness less than a few nanometers have recently been investigated as a new class of protective coatings. 2D materials such as graphene and h-BNNS are among the most studied ones, since they have many desirable properties such as high mechanical strength and flexibility [1, 2], high thermal conductivity [3], impermeability to water and gases [4], and high optical transparency [5]. Most importantly, being atomically thin, these 2D materials will not affect applications that require high levels of dimension precision.

h-BNNS and graphene, however, also have different physical and chemical properties, with the former being highly stable in air at elevated temperatures and electrically insulating. Due to high electrical conductivity, graphene actually contributes to the formation of galvanic cells with the underlying metal substrates, thus accelerating the corrosion process over long terms [6]. In comparison, h-BNNS also has excellent chemical stability in various aquatic environments [7]. Furthermore, hexagonal boron nitride nanomaterials are non-cytotoxic and have higher levels of biocompatibility when compared to their carbon counterparts [8-11]. In a recent study, a 130 μm thick h-BN coating was used as a protection layer of a solar probe owing to h-BN's stability at high temperatures and low ratios of the solar absorptivity to the emissivity [12]. All these properties render h-BNNS a desirable protective coating that can be used in harsh environments.

Due to its high reflectivity in the UV-visible range, Ag mirrors are believed to be a great choice in astronomical telescopes in earth-based observatories [13]. However, Ag slowly tarnishes in air as the consequence of reaction with sulfur containing compounds especially H_2S , producing black Ag_2S on the surface resulting in reduced reflectivity, and added electrical resistance [14]. Methods such as polishing and soaking in a solution of sodium bicarbonate will remove the Ag_2S , but can also cause irreversible material loss and create micro-pits, which will eventually lead to further corrosion. Tarnish inhibitors such as chromate conversion coatings are effective, but the process usually involves highly toxic hexavalent chromium compounds [15]. Atomic layer deposition of common barrier layers such as AlO_x is also incompatible with Ag because this process can cause partial oxidation on Ag surface, which will compromise the reflectivity [13]. Therefore, the research on ultra-thin protective coatings with non-toxic materials that are compatible with Ag as corrosion inhibitors is of great importance.

Studies have been carried out on CVD synthesis of h-BNNS on certain facets of single crystal Ag [16-18], but the h-BNNS growth on widely available polycrystalline Ag foil via a relatively simple atmospheric pressure (AP)-CVD process has been rarely reported. While most anti-corrosion studies utilizing 2D materials were conducted on copper, nickel, and stainless steel [19-23], the anti-corrosion behavior of h-BNNS thin film on commercial Ag foil has not been studied before. In this work, we show that high-quality h-BNNS can be grown on polycrystalline Ag foils via AP-CVD, without affecting the optical properties of the Ag surface. We also show that the protected Ag shows enhanced anti-corrosion properties against H_2S .

EXPERIMENTAL

Growth of h-BNNS thin films by CVD on Ag

The h-BNNS thin films were grown on Ag foil (0.1 mm thick, 99.9% purity, Sigma-Aldrich) by AP-CVD in a horizontal tube furnace. The growth temperatures were set to 940°C for solid Ag and 970°C for melted Ag. Prior to the growth, Ag foils were annealed under 5% hydrogen in argon at 940°C for 5 hours to remove volatile impurities. During each growth, 100 mg of ammonia borane (98%, United Boron) was heated to 120°C to generate borazine gas. The substrates were then exposed to borazine for 20 minutes at the growth temperatures. For the growth on melted Ag, cobalt foil (0.1 mm thick, 99.95% purity, Sigma-Aldrich) was employed as the supporting layer due to its superior wettability towards Ag.

Transferring h-BNNS thin films to TEM grids

In this work, a polymethyl methacrylate (PMMA) assisted transfer method was employed. Typically, a layer of PMMA was coated on h-BNNS/Ag by a spin coater before it was submerged in 1 M iron(III) nitrate aqueous solution overnight. After etching, the PMMA/h-BNNS floated on the solution and was washed with deionized water several times. After that, the PMMA/h-BNNS was transferred to a TEM grid. Finally, the PMMA was removed by soaking in acetone.

Anti-corrosion tests in H₂S

H₂S gas was generated by dropwise addition of 6M HCl onto sodium sulfide, and delivered to a vessel containing one h-BNNS-coated Ag and one bare Ag foil. The output stream of the reactor was connected to a gas bubbler containing ~ 50 mL of saturated aqueous sodium carbonate. Prior to, and after H₂S generation, the system was purged with argon to remove air or excess H₂S. The total exposure time was two hours.

Characterization

Scanning electron microscopy (SEM) was conducted on JEOL-7500 equipped with a field emission gun. The SEM was operated at 1kV for imaging to minimize the depth of beam specimen interaction. X-ray photoelectron spectroscopy (XPS) was carried out directly on the silver foil using a PHOIBOS 100 hemispherical analyzer with an Al K α source. Transmission electron microscopy (TEM)/scanning transmission electron microscopy (STEM) was performed on JEOL ARM 200F with an accelerating voltage of 80 kV. Diffuse reflectance spectra were acquired using a custom setup with detailed experimental information in the Supporting Information.

RESULTS AND DISCUSSION

CVD growth of h-BNNS on silver

In this work, h-BNNS thin film was grown on Ag substrates by AP-CVD, using ammonia borane as the precursor. The schematic of h-BNNS growth is shown in Figure 1. Solid and melted Ag substrates were employed as the substrates, respectively. For the growth on melted Ag substrate,

the wettability between the melted substrate and underlying metal support is crucial. In this case, cobalt is chosen as the underlying metal support due to its superior wettability against melted Ag. Moreover, Co and Ag are almost insoluble in each other in both solid and liquid state according to the phase diagrams [24, 25]. Therefore, the underlying Co support and the melted Ag will not form alloys which would otherwise introduce a variant to the h-BNNS growth.

Figure 2a and b show the SEM images of h-BNNS grown on solid and melted Ag substrates, respectively. The dark regions in the SEM images are the underlying Ag substrate, while h-BNNS shows different shades of grey. Since h-BNNS is insulating, the thicker film appears brighter due to charging while the thinner section looks slightly darker. More SEM images are provided in the Supporting Information (Figure S2). Comparing with h-BNNS grown on solid Ag, h-BNNS on melted Ag appears to be more uniform and contains less defects such as cracks and holes. This is because melting effectively removes surface discontinuities such as grain boundaries and surface defects, which act as the nucleation sites during early stage of the growth [26-28]. In addition, melting would create a better homogeneity in the Ag surface leading to uniform nucleation, in contrast to the localized nucleation around grain boundaries and surface defects in solid Ag. All these contribute to a growth of h-BNNS film with less defects.

XPS (Figure 2c-e) was employed to investigate the chemical composition and stoichiometry between B and N atoms. For h-BNNS films grown on solid and melted Ag, B 1s peak situated at 190.8 eV and N 1s peak at 398.0 eV are observed for both samples, which are in good agreement with the published results [29-31]. The ratio between B and N atoms calculated from the spectra is close to 1, indicative of 1:1 stoichiometry in sp^2 hybridized BN.

The selected area electron diffraction (SAED) pattern (Figure 2f) from a small region with a diameter of 100 nm suggests that the h-BNNS has a polycrystalline nature. A high-resolution Bright Field STEM image at the edge (Figure 2g) reveals that h-BNNS grown on melted Ag substrates is of few-atomic-layer thickness. The interlayer distance measured is 0.34 nm which is consistent with h-BN's (0002) spacing. The Fast Fourier Transform (FFT) image in the inset containing several sets of dots also verifies that h-BNNS is few-atomic-layer [2, 29]. High angle angular dark field (HAADF) imaging is a powerful technique that can differentiate individual atoms according to their Z contrast [32], with the heavier the atom the higher intensity in the HAADF image. STEM-HAADF image of a monolayer region (Figure S1d) clearly shows the honeycomb structure of alternating B and N atoms, with B atoms associated with the darker spots and N atoms with the brighter ones. Furthermore, electron energy loss spectroscopy (EELS) was employed to determine the chemical state of B and N. The EELS spectrum (Figure 2h) shows two bands starting at 188 and 398 eV, corresponding respectively to K-shell ionization edge of B and N. Each band shows well-resolved $1s-\pi^*$ and $1s-\sigma^*$ antibonding orbits indicating a sp^2 hybridized h-BN structure [33]. Highly crystalline h-BN can generate a sharp Raman band at $\sim 1366\text{ cm}^{-1}$, but its intensity is much lower than its carbon counterpart [34]. Due to the low crystallinity and few-atomic-layer thickness, h-BN characteristic Raman G band was not observed using a 632.81 nm laser source.

There is invisible difference in appearance between the h-BNNS grown on solid Ag (denoted h-BNNS_Ag) and bare annealed Ag (Bare_Ag). Diffused reflectance spectra were collected to assess if the h-BNNS protective coating alters the optical property of Ag. The spectra (Figure 3)

demonstrate that the h-BNNS_Ag and Bare_Ag show only minor difference (~2.5%) in the reflectance in the UV-visible light range. The h-BNNS-coated Ag reflects UV-Visible light effectively due to a couple of reasons. Firstly, h-BN itself has a large bandgap of around 5.5 eV, which means the coating does not absorb light with wavelength longer than 215 nm [35]. Secondly, the h-BNNS is only few-atomic-layer thick and therefore has a high level of transparency to the light. Furthermore, h-BN is atomically flat where the hexagons are aligned in a nearly perfect atomic plane, which does not negatively interfere with reflection. Note that the reflectance is relatively low compared to Ag films or coatings purposely prepared for mirrors [13, 36]. This is because that the Ag foils used in this research were produced via metal rolling which leaves many surface defects such as strips and pinholes, affecting the reflectivity. Therefore, it is reasonable to say that h-BNNS coatings would not affect the application of Ag as mirrors.

Anti-corrosion performance

Ag is susceptible to tarnishing due to sulfide formation even in natural conditions where H₂S concentration is very low (0.001-0.005 ppm) [37, 38]. To assess the efficacy of the h-BNNS protective film, corrosion tests were conducted in a flask filled with H₂S gas in damp environment. Despite the quality of h-BNNS grown on melted Ag substrate is better, from a practical point of view, h-BNNS grown on solid Ag was used for the anti-corrosion tests. On solid Ag, h-BNNS tends to have more defects such as cracks and holes (Figure 2a and 2b).

The h-BNNS_Ag and Bare_Ag were placed next to each other in a flask filled with H₂S. After 30-minute exposure, the bare Ag foil (denoted Bare_Ag_H₂S) showed highly visible

decolorization. The initial shiny surface with metallic glare gradually darkened. After two hours of exposure, the surface of bare Ag foil showed a brownish color. In comparison, the surface color and metallic luster of the coated foil (denoted h-BNNS_Ag_H₂S) almost remained the same. Optical images (Figure 4) collected are in line with the visual observation. Noticeably, the color of certain crystal grains is darker than others in the Bare_Ag_H₂S sample. This indicates that certain exposed facets of Ag are more reactive towards H₂S [39]. In comparison, the uniformity of color of the h-BNNS_Ag_H₂S is indicative of minimal tarnishing. Moreover, based upon SEM studies (Figure S4), the surface of Bare_Ag appears to be textured due to formation of nanoparticles after H₂S exposure, while the surface morphology of h-BNNS_Ag_H₂S remains largely unchanged.

Diffuse reflectance spectra (Figure 5) were collected to evaluate the impact of H₂S exposure on the reflectivity of Ag. The Bare_Ag_H₂S sample shows a significant decrease in reflectance in the visible range after the exposure. On the contrary, h-BNNS_Ag_H₂S shows only a minor reflectivity decrease with respect to samples without exposure, indicating that BNNS thin films effectively protects Ag substrate. The attenuation in reflectance of h-BNNS_Ag and Bare_Ag in Figure 3 appears to be slightly lower than those shown in Figure 5. This is likely due to the different spots (circles with 1mm radius) selected for acquiring the spectra. The commercial Ag foils used in this research were not polished. Therefore, the surface defects such as scratches and pinholes can affect the reflectivity of samples. XPS spectra of Bare_Ag_H₂S and h-BNNS_Ag_H₂S (Figure 6) reveal the intensity difference of S 2p and 2s peaks. The atomic ratio of S to Ag can be calculated from the spectra. The Bare_Ag_H₂S has a S to Ag ratio of 0.215 which is 5 times higher than that of the h-BNNS_Ag_H₂S sample. The Ag XPS spectra consist of two peaks, Ag 3d_{5/2} and Ag 3d_{3/2},

among which Ag 3d_{5/2} is often used when discussing the formation of Ag⁺ [37, 40, 41]. Based upon deconvolution, Ag 3d_{3/2} shows no significant difference in the components, whereas, for the Ag 3d_{5/2} peak, a remarkably larger component situated at 377.7 eV, 0.4 eV lower than the Ag metallic peak, is found for the Bare_Ag_H₂S, attributing to a large quantity of Ag₂S formed on the surface [37, 42].

As noted above, h-BNNS films grown on solid Ag tends to have more cracks and holes, which expose Ag to H₂S during the tests. The quality of h-BNNS films is affected by the physical features of Ag surface including grain boundaries and defects, which in turn determined by how the Ag items are produced, such as rolling, casting, and physical vapor deposition. Commercial Ag mirrors produced by deposition are relatively free of defects and are expected to lead to high quality h-BNNS films, which are expected to exert better protection on the underlying mirrors. Transferring h-BNNS to commercial Ag items can protect them from tarnishing to some degree. However, transferring CVD films is a laborious task. The quality of the transferred films often suffers due to contamination from the etching solution and damage caused by mechanical forces exerted on the films. Using h-BNNS directly grown on the substrate for protection is a relatively simple and practical process.

CONCLUSION

In this work, atomically thin h-BNNS was successfully grown on solid and melted Ag substrates, respectively, via AP-CVD using ammonia borane as a precursor. The h-BNNS grown on melted

Ag appears to be continuous and uniform in thickness because the melting process effectively removes highly sporadic defects and impurities that act as nucleation sites. The ultra-thin h-BNNS on solid Ag substrate poses negligible impact on metallic luster and appearance. In accelerated corrosion tests, the Ag substrate coated by h-BNNS showed invisible optical color change under high concentration of H₂S, while bare Ag displayed drastic color change within two hours of exposure. XPS analysis reveals that sulfide formation was largely suppressed for the coated Ag substrate, which means the h-BNNS coating effectively impedes Ag tarnishing in an environment with high level of H₂S. These results suggest that h-BNNS can be grown on Ag substrate and it is a good candidate as an ultra-thin protective coating against Ag tarnishing. It is expected that the high chemical stability and thermal stability of h-BNNS will also make it an effective coating for Ag mirrors that are used at elevated temperatures and other corrosive environments.

FIGURES

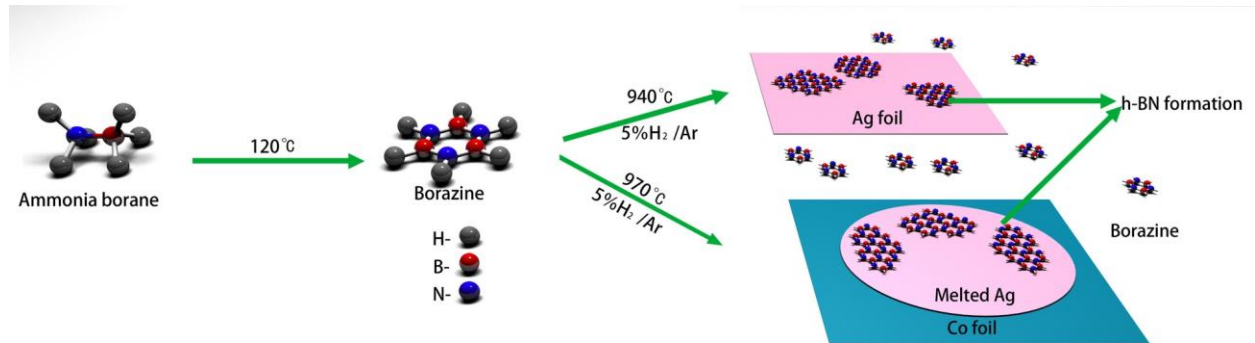


Figure 1. Schematic of h-BNNS growth on both solid and melted Ag substrates.

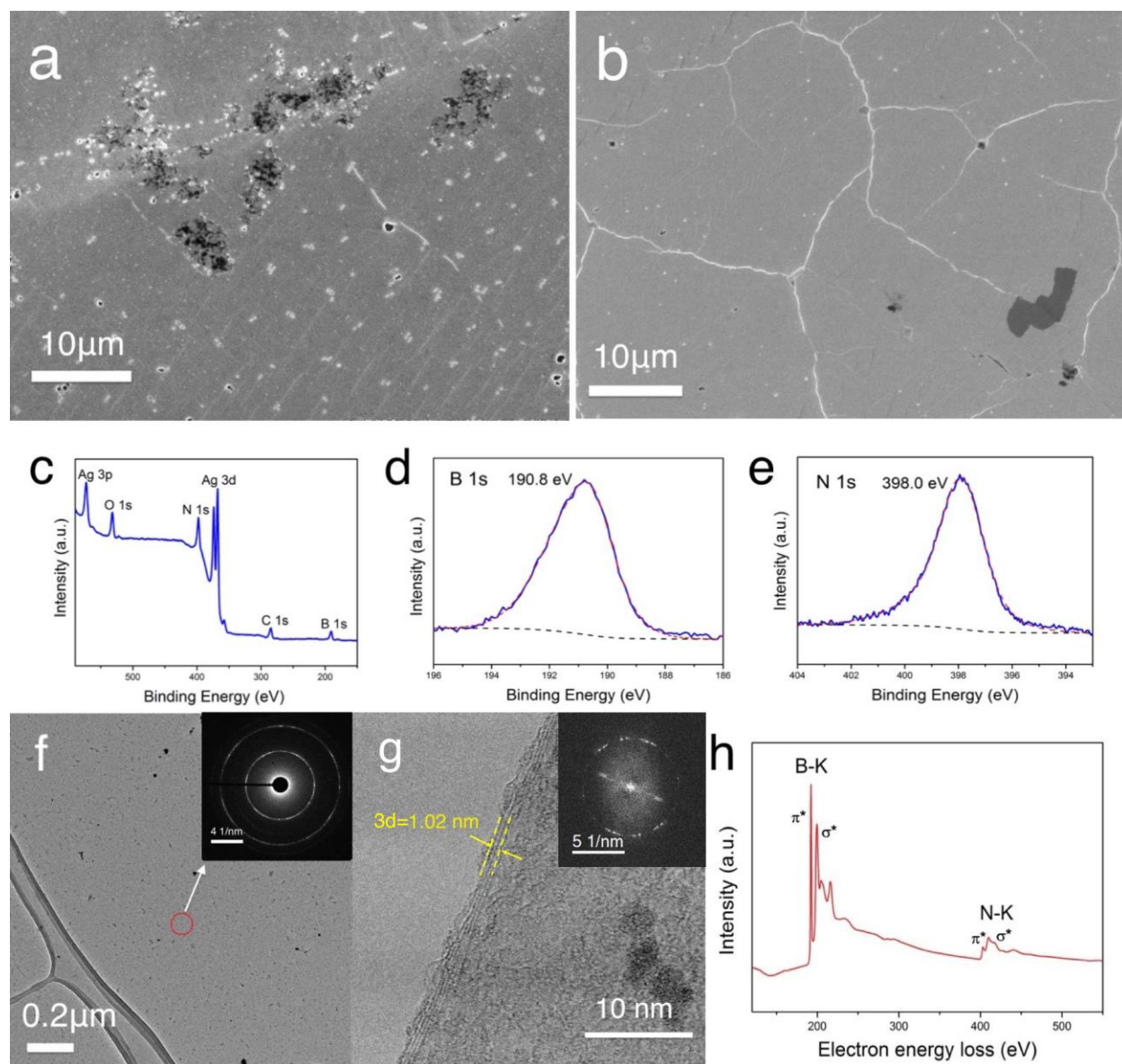


Figure 2. Characterization of h-BNNS grown on Ag substrates. (a) and (b) SEM images of h-BNNS grown on solid and melted Ag substrates, respectively. (c), (d) and (e) XPS survey, B 1s and N 1s spectra of h-BNNS. (f) TEM image and SAED pattern (inset) of a region with a diameter of 100 nm on h-BNNS. (g) High resolution Bright Field STEM image and the FFT pattern (inset) of h-BNNS. (h) EELS spectrum.

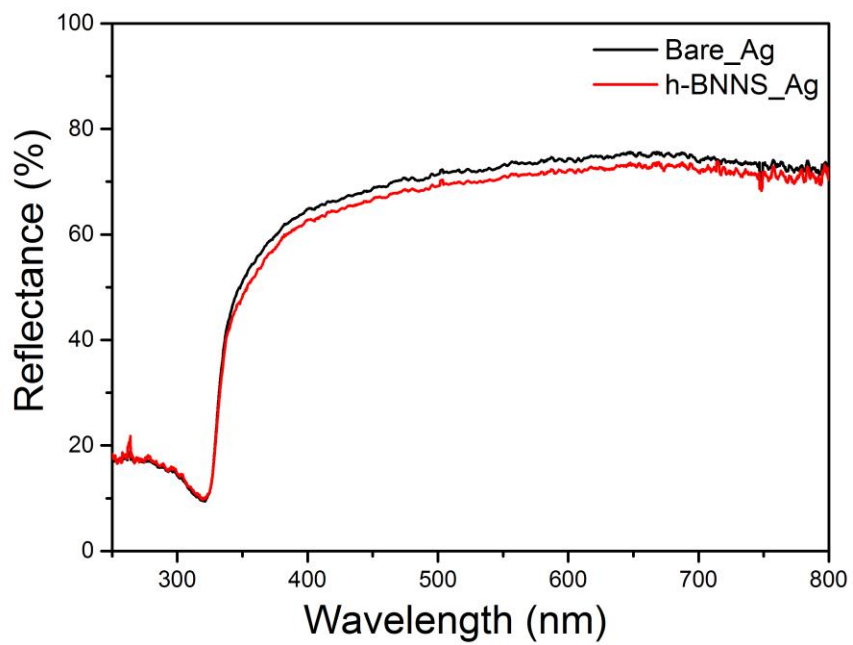


Figure 3. UV-Vis diffuse reflectance spectra of annealed Ag (Bare_Ag) and h-BNNS-coated Ag (h-BNNS_Ag).

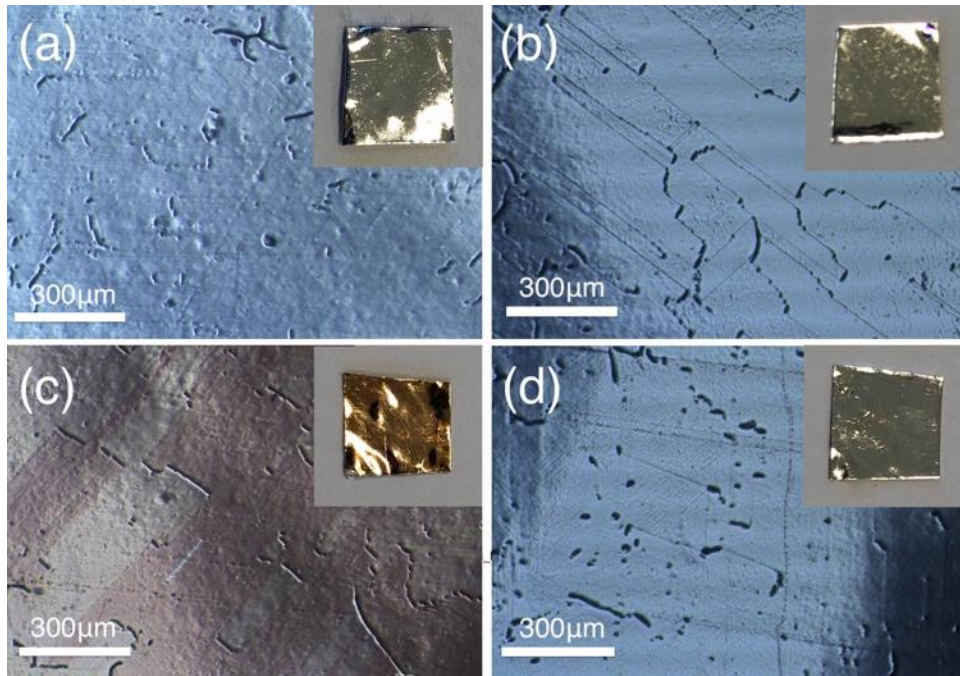


Figure 4. Optical images of (a) Bare_Ag; (b) h-BNNS_Ag; (c) Bare_Ag_H₂S; (d) h-BNNS_Ag_H₂S. Insets are photos taken by a digital camera.

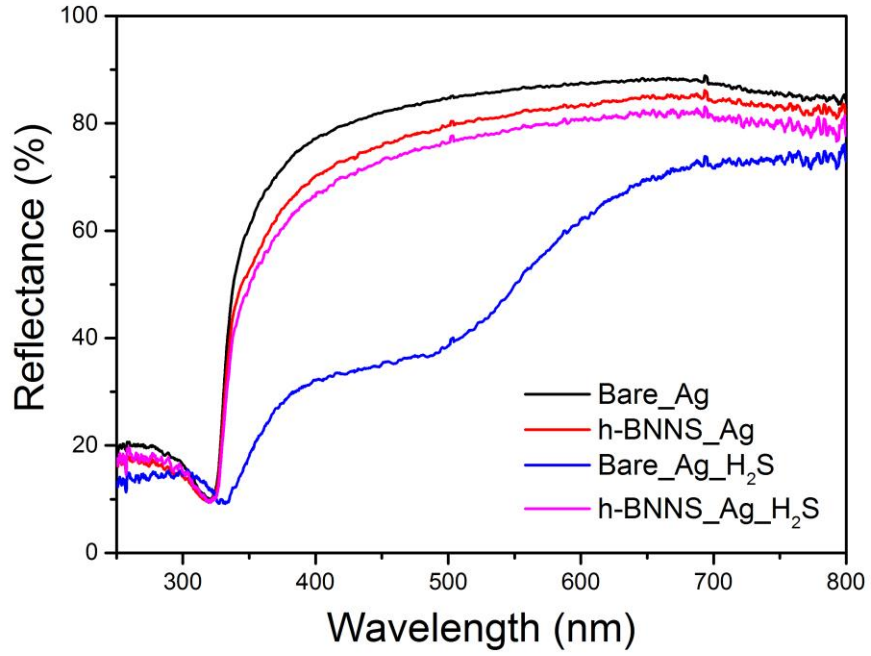


Figure 5. UV-Vis diffuse reflectance spectra for Bare_Ag, h-BNNS_Ag, Bare_Ag_H₂S and h-BNNS_Ag_H₂S.

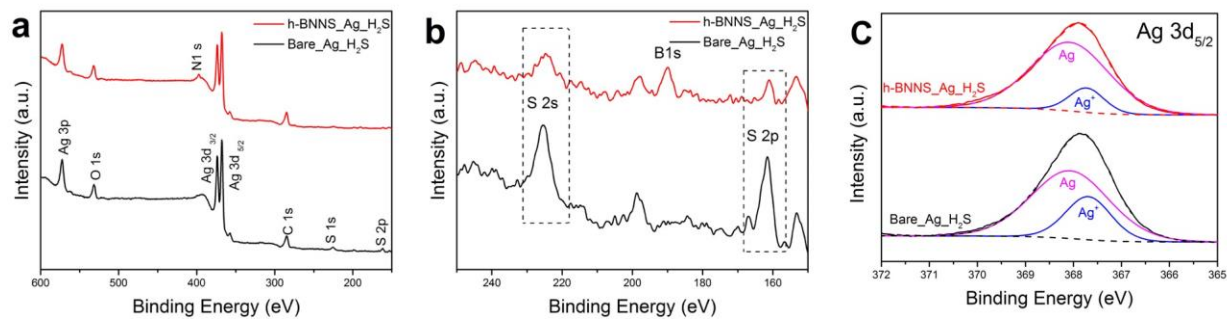


Figure 6. XPS spectra of Bare_Ag_H₂S and h-BNNS_Ag_H₂S. (a) survey spectra; (b) S 2s and S 2p peaks; (c) Ag 3d_{5/2} peaks with metallic Ag and Ag⁺ components.

ASSOCIATED CONTENT

Supporting information 1: UV-Vis custom setup details, Atomic resolution TEM images, SEM contrast explanation, digital photos of corrosion experiments, SEM images showing fine morphological change after H₂S exposure and Ag XPS spectra. (docx)

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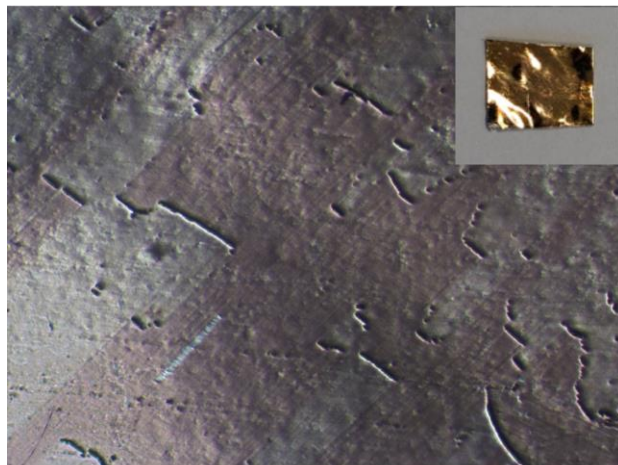
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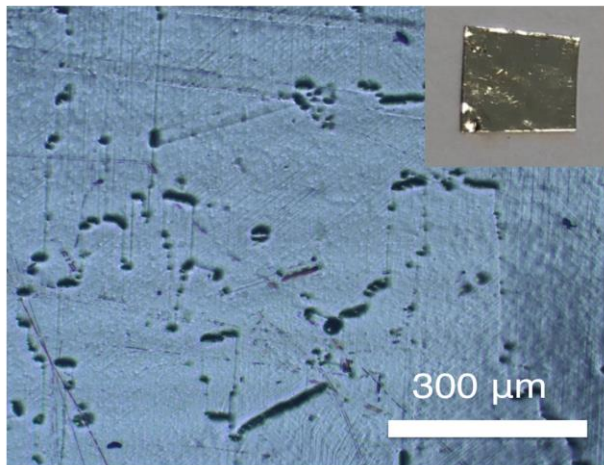
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Bare silver foil



h-BNNS-coated silver foil



After 2 hours of H₂S exposure